

# **Device Modeling Report**

COMPONENTS:  
DIODE/ SCHOTTKY RECTIFIER / STANDARD  
PART NUMBER: EC10QS09  
MANUFACTURER: NIEC

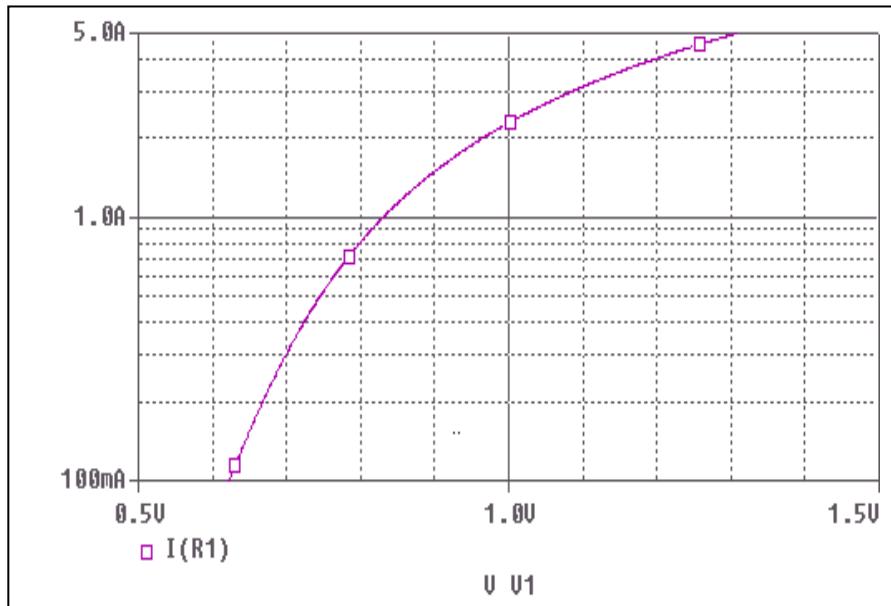


**Bee Technologies Inc.**

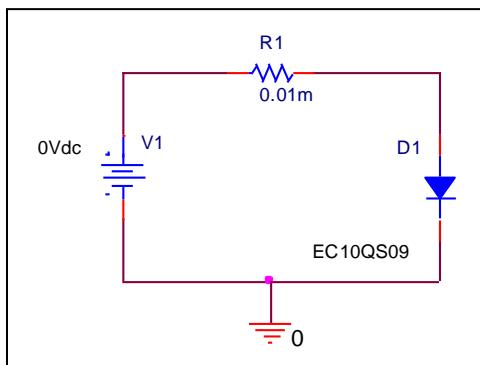
PSpice model parameter	Model description
IS	Saturation Current
N	Emission Coefficient
RS	Series Resistance
IKF	High-injection Knee Current
CJO	Zero-bias Junction Capacitance
M	Junction Grading Coefficient
VJ	Junction Potential
ISR	Recombination Current Saturation Value
BV	Reverse Breakdown Voltage(a positive value)
IBV	Reverse Breakdown Current(a positive value)
TT	Transit Time
EG	Energy-band Gap

## Forward Current Characteristic

Circuit Simulation Result

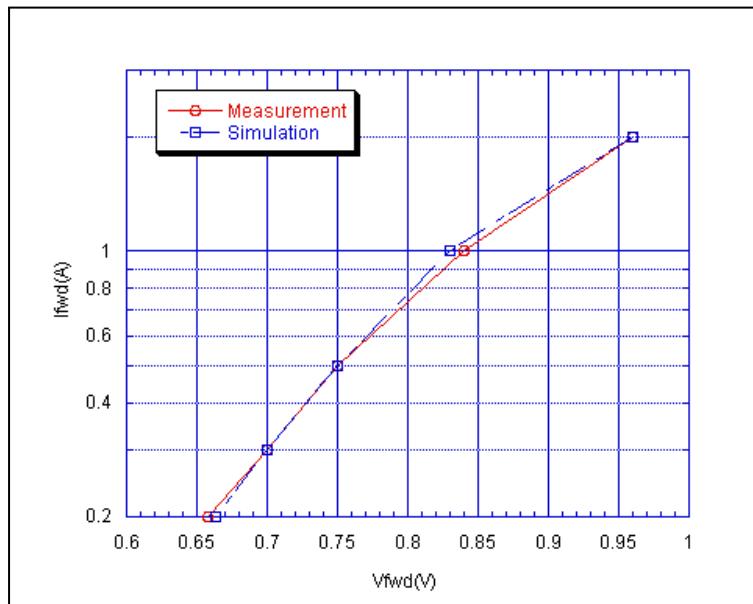


Evaluation Circuit



## Comparison Graph

### Circuit Simulation Result

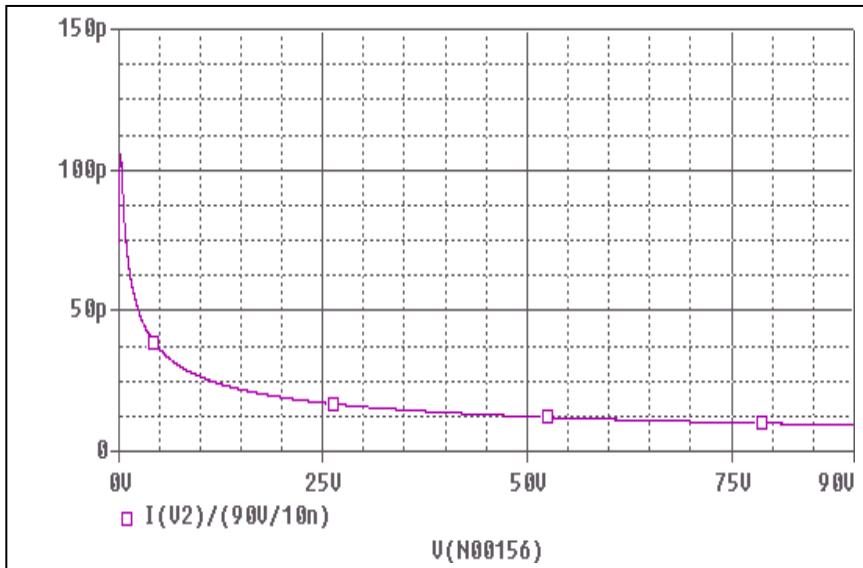


### Simulation Result

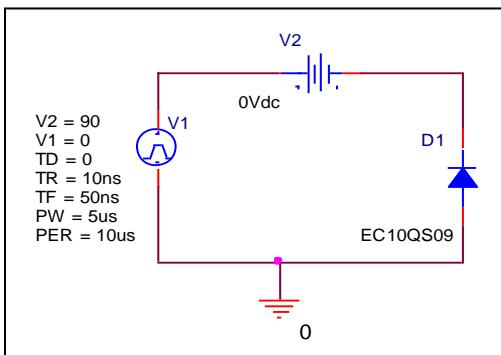
$I_{fwd}$ (A)	$V_{fwd}$ (V) Measurement	$V_{fwd}$ (V) Simulation	%Error
0.2	0.658	0.663	0.76
0.5	0.750	0.745	-0.67
1	0.840	0.830	-1.19
2	0.960	0.958	-0.21

## Junction Capacitance Characteristic

### Circuit Simulation Result

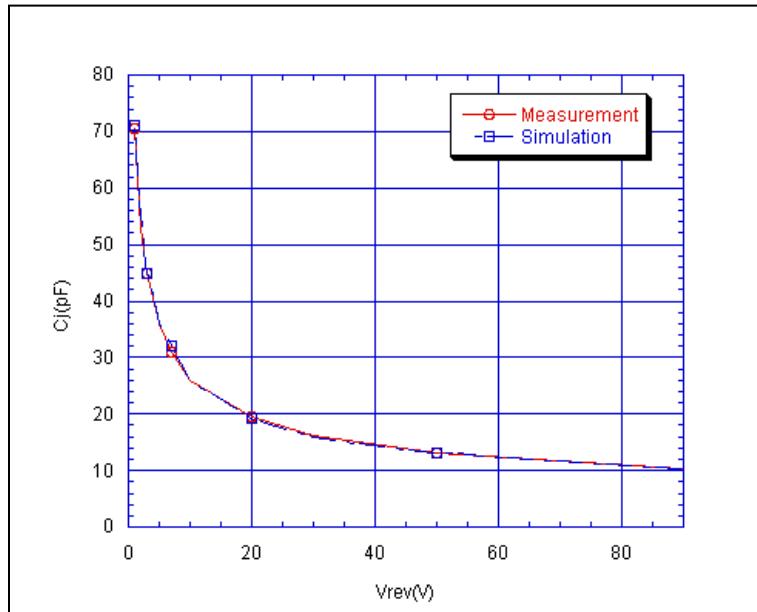


### Evaluation Circuit



## Comparison Graph

Circuit Simulation Result



Simulation Result

Vrev(V)	Cj(pF) Measurement	Cj(pF) Simulation	%Error
1	70.500	71.000	0.71
2	53.000	55.000	3.77
5	36.000	35.770	-0.64
10	26.000	25.889	-0.43
20	19.400	19.300	-0.52
50	13.000	12.972	-0.22
90	10.000	9.988	-0.12